AMENDMENTS TO THE SPECIFICATION

IN THE TITLE OF INVENTION:

Please amend the title as it appears on the first page of the specification and in the U.S. Patent and Trademark Office's records, as follows:

--SEMICONDUCTOR STRUCTURE WITH <u>LINING LAYER</u>
PARTIALLY ETCHED <u>ON SIDEWALL OF THE</u> GATE—AND METHOD—OF
FABRICATING THE SAME—